SPECIFICATION

Please rewrite the title as –METHOD OF FACBRICATING A CAPACITOR HAVING SIDEWALL SPACE PROTECTING THE DIELECTRIC LAYER—.

At page 18 of the specification, please rewrite the Abstract as follows:

A capacitor structure includes is fabricated by forming a bottom plate, forming a dielectric layer overlaying the bottom plate, and forming a top plate over the, and a dielectric layer between the bottom and top plates. In addition, at least one insulating sidewall spacer that protects the dielectric layer during processing is formed along the perimeter of the top plate and overlaying a portion of the dielectric layer.